



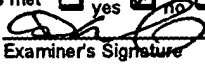

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SERIAL NUMBER 10/669,898	FILING DATE 09/24/2003  RULE	CLASS 438	GROUP ART UNIT 2824	ATTORNEY DOCKET NO. YOR920030469US1	
APPLICANTS  Cyril Cabral JR., Ossining, NY;  Meikei leong, Wappingers Falls, NY; Jakub T. Kedzierski, Peekskill, NY;  ** CONTINUING DATA ***** none CDW  ** FOREIGN APPLICATIONS ***** none CDW  IF REQUIRED, FOREIGN FILING LICENSE GRANTED ** 12/30/2003					
Foreign Priority claimed <input type="checkbox"/> yes <input checked="" type="checkbox"/> no 35.U.S.C. 119 (a-d) conditions met <input type="checkbox"/> yes <input checked="" type="checkbox"/> no <input type="checkbox"/> Met after Allowance Verified and Acknowledged  Examiner's Signature  Initials		STATE OR COUNTRY NY	SHEETS DRAWING 3	TOTAL CLAIMS 30	INDEPENDENT CLAIMS 2
ADDRESS Moser, Patterson & Sheridan Suite 100 595 Shrewsbury Avenue Shrewsbury, NJ 07702					
TITLE Method and apparatus for fabricating CMOS field effect transistors					
FILING FEE	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT		<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees ( Filing ) <input type="checkbox"/> 1.17 Fees ( Processing Ext. of time )		